



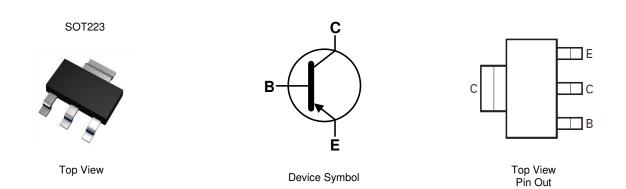
#### 25V PNP MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

### **Features and Benefits**

- $BV_{CEO} > -25V$
- Maximum Continuous Current I<sub>C</sub> = -4A
- Peak Pulse Current I<sub>C</sub> = -10A
- High Gain Holds Up hFE > 195 @IC = -2A
- Very Low Equivalent On-Resistance; R<sub>CE(sat)</sub> = 130mΩ at -2A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.112 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT1149ATA	AEC-Q101	FZT1149A	7	12	1,000
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

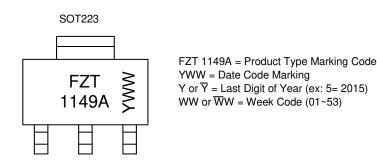
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**





### Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-4	А
Base Current	Ι <sub>Β</sub>	-500	mA
Peak Pulse Current	ICM	-10	А

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	e Unit		
	(Note 5)		3.0		
Dower Dissinction	(Note 6)	D	2.0	w	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2	1	
	(Note 5)		41.7		
Thermal Desistance, Junction to Ambient	(Note 6)	P	62.5		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ extsf{ heta}JA}$	78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	$R_{ ext{ heta}JL}$	10.9		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

#### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as note (5), except the device is mounted on 25mm x 25mm 2oz copper.

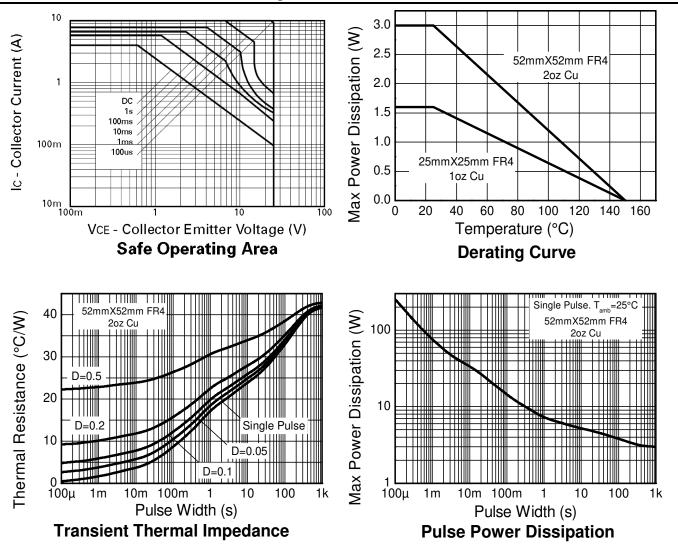
7. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

8. Same as note (5), except the device is mounted on minimum recommended pad layout.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





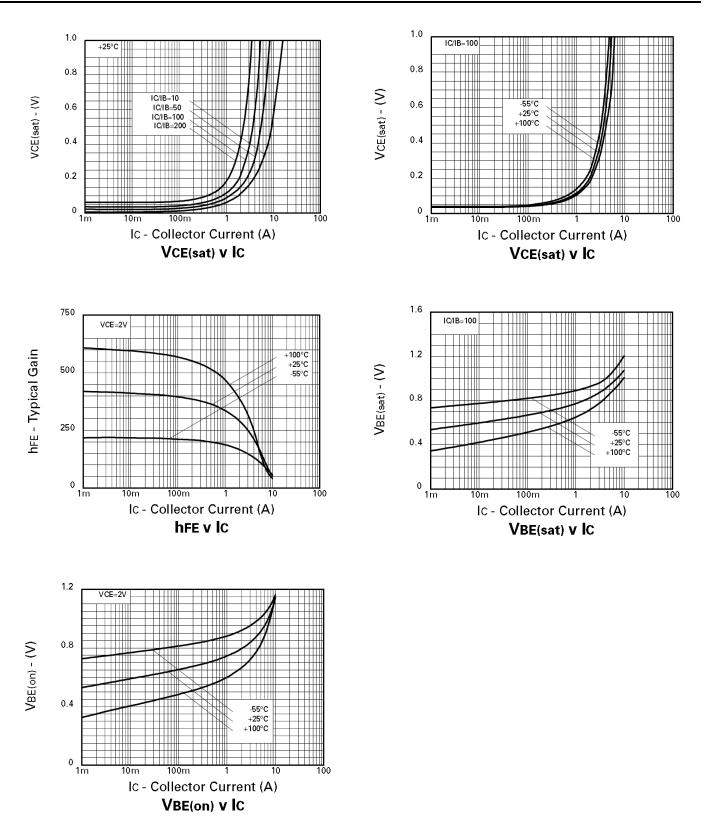
# Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-30	-70	-	V	$I_{\rm C} = -100 \mu \text{A}$
Collector-Emitter Breakdown Voltage	BVCES	-25	-60	-	V	$I_{\rm C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BVCEO	-25	-60	-	V	$I_{\rm C} = -10 \text{mA}$
Collector-Emitter Breakdown Voltage	BVCEV	-25	-60	-	V	$I_{\rm C} = -100 \mu A, V_{\rm EB} = -1V$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.5	-	V	$I_{F} = -100 \mu A$
Collector Cut-Off Current	ICBO	-	-0.3	-20	nA	$V_{CB} = -24V$
Collector Cut-Off Current	ICES	-	-0.3	-20	nA	V <sub>CES</sub> = -24V
Emitter Cut-Off Current	I <sub>EBO</sub>	-	-0.3	-20	nA	$V_{EB} = -6V$
		270	450	-		$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$
	h <sub>FE</sub>	250	400	800	-	$I_{C} = -0.5A, V_{CE} = -2V$
DC Current Transfer Static Ratio (Note 11)		195	320	-		$I_{C} = -2A, V_{CE} = -2V$
		115	190	-		$I_{C} = -5A, V_{CE} = -2V$
			50	-		$I_{C} = -10A, V_{CE} = -2V$
		-	-45	-80		I <sub>C</sub> = -0.1A, I <sub>B</sub> =-1mA
		-	-100	-170		$I_{\rm C} = -0.5$ A, $I_{\rm B} = -3$ mA
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	-	-140	-240	mV	$I_{C} = -1A, I_{B} = -7mA$
		-	-170	-260		$I_{C} = -2A, I_{B} = -30mA$
		-	-230	-350		$I_{\rm C} = -4A, I_{\rm B} = -140 {\rm mA}$
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	-	-960	-1,050	mV	$I_{C} = -4A, I_{B} = -140mA$
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	-	-860	-1,000	mV	$I_{C} = -4A, V_{CE} = -2V$
Transitional Frequency	f <sub>T</sub>	-	135	-	MHz	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}, f = 50 \text{MHz}$
Output Capacitance	C <sub>obo</sub>	-	50	-	pF	$V_{CB} = -10V, f = 1MHz,$
Switching Time	t <sub>on</sub>	-	150	-	ns	$V_{CC} = -10V, I_C = -4A,$
	t <sub>off</sub>	-	270	-	ns	$I_{B1} = I_{B2} = \pm 40 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .



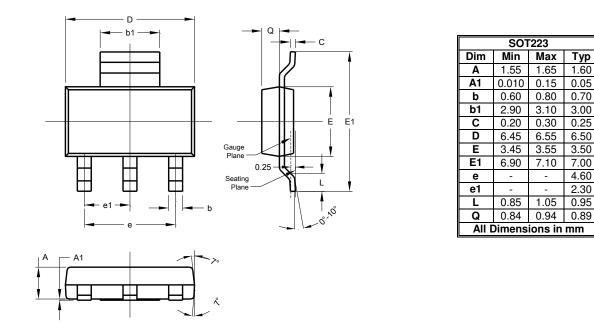
### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





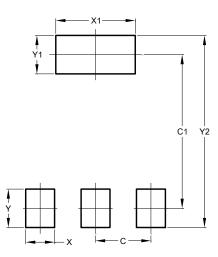
### **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



<b>D</b> : .	
Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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